RT3K33M

Composite Transistor
For high speed switching
Silicon N-channel MOSFET

DESCRIPTION

RT3K33M is a composite transistor built with two INK0003AX chips in SC-88 package.

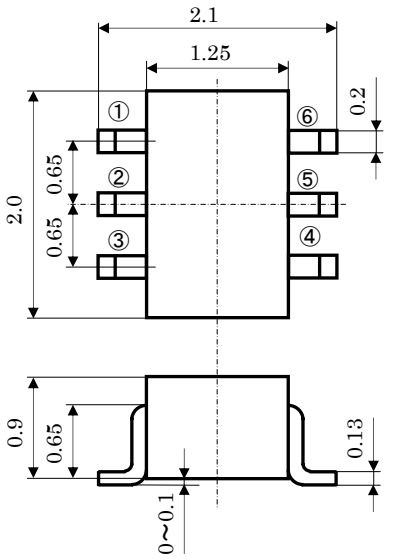
FEATURE

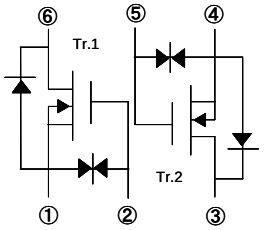
・Input impedance is high, and not necessary to consider a drive electric current.
・Vth is low, and drive by low voltage is possible. Vth=0.6～1.2V
・Low on Resistance. Ron=0.9Ω(TYP)
・High speed switching.
・Small package for easy mounting.

APPLICATION

high speed switching , Analog switching

OUTLINE DRAWING Unit:mm





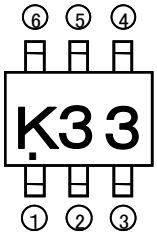
TERMINAL CONNECTOR
①:SOURCE1
②:GATE1
③:DRAIN2
④:SOURCE2
⑤:GATE2
⑥:DRAIN1

JEITA:SC-88

MAXIMUM RATING (Ta=25℃)

SYMBOL	PARAMETER	RATING	UNIT
V_{DSS}	Drain-source voltage	20	V
V_{GSS}	Gate-source voltage	±8	V
I_D	Drain current	200	mA
P_D	Total power dissipation(Ta=25℃)	150	mW
T_{ch}	Channel temperature	+125	℃
T_{stg}	Range of Storage temperature	-55～+125	℃

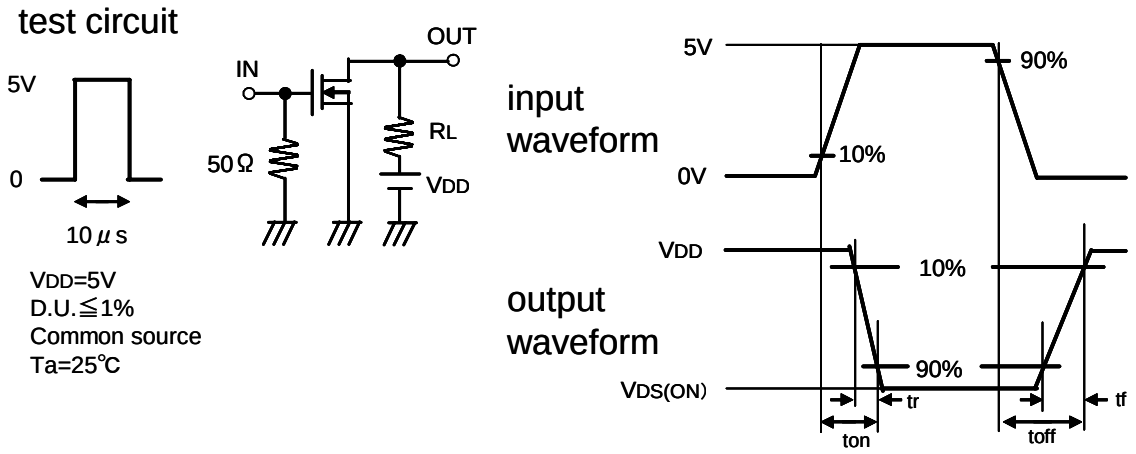
MARKING



ELECTRICAL CHARACTERISTICS (Ta=25℃)

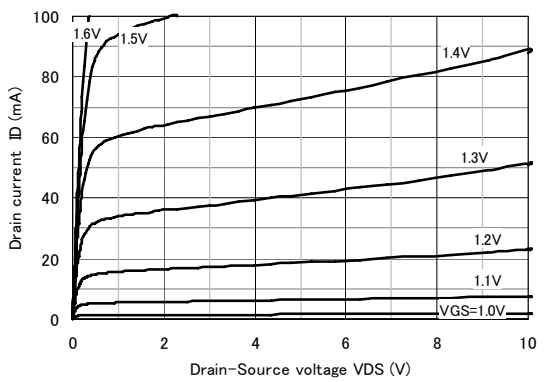
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$V_{(BR)DSS}$	Drain-source breakdown voltage	I_D=100μA, V_{GS}=0V	20	–	–	V
I_{GSS}	Gate-source leak current	V_{GS}=±5V, V_{DS}=0V	–	–	±0.5	μA
I_{DSS}	Zero gate voltage drain current	V_{DS}=20V ,V_{GS}=0V	–	–	50	μA
V_{th}	Gate threshold voltage	I_D=250μA, V_{DS}= V_{GS}	0.6	–	1.2	V
$\|Y_{fs}\|$	Forward transfer admittance	V_{DS}=10V, I_D=0.1A	–	300	–	mS
$R_{DS(ON)}$	Static drain-source on-state resistance	I_D=100mA, V_{GS}=4.0V	–	0.9	–	Ω
C_{iss}	Input capacitance	V_{DS}=10V, V_{GS}=0V,f=1MHz	–	34	–	pF
C_{oss}	Output capacitance	V_{DS}=10V, V_{GS}=0V,f=1MHz	–	8.5	–	pF
t_{ON}	Switching time	V_{DD}=5V , I_D = 10mA V_{GS}=0～5V	–	14	–	ns
t_{OFF}			–	85	–	

Switching time test condition

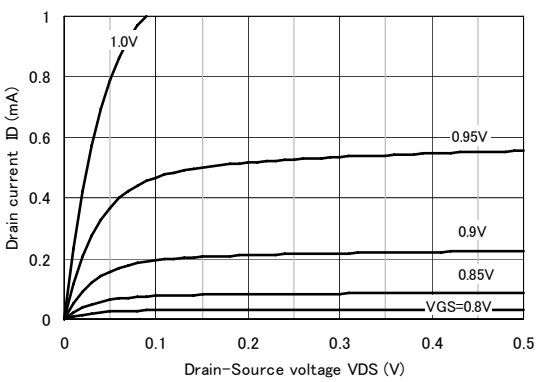


TYPICAL CHARACTERISTICS

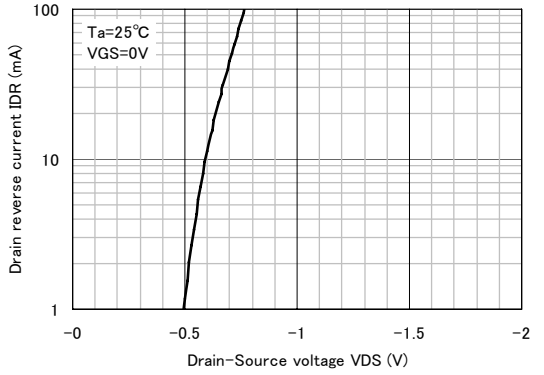
ID -VDS



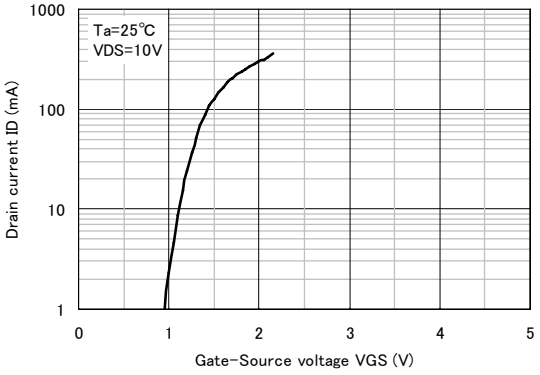
ID -VDS(Low voltage region)



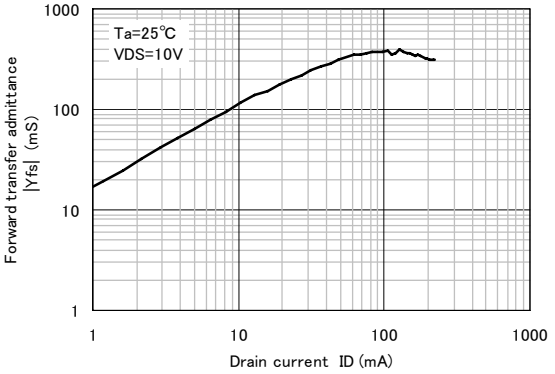
IDR -VDS



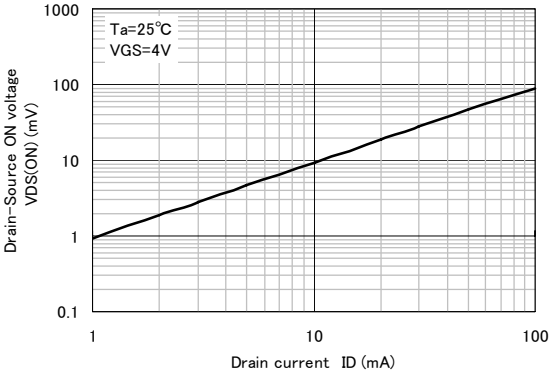
ID -VGS



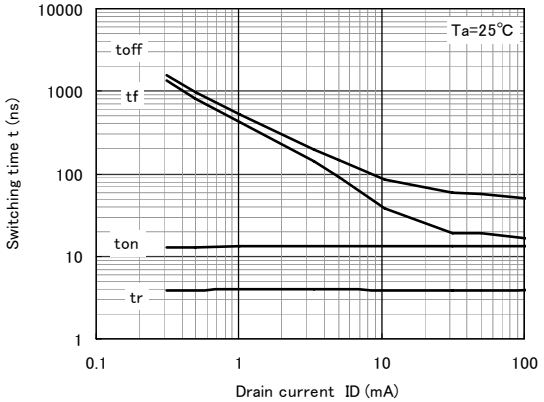
|Yfs| - ID



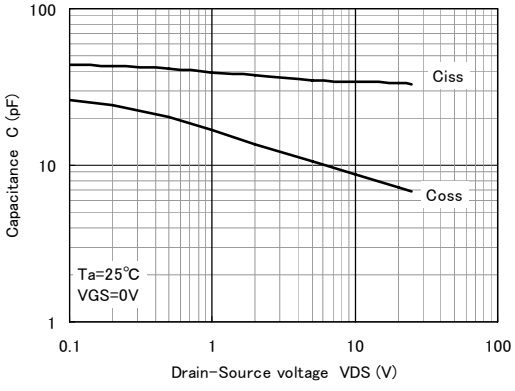
VDS(ON) -ID



t - ID



C - VDS



ISAHAYA ELECTRONICS CORPORATION

Marketing division, Marketing planning department

6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

Keep safety first in your circuit designs!

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

Notes regarding these materials

·These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party.

·ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.

·All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed herein.

·ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.

·The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials.

·If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

·Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.

Apr.2007